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(54) **RELAY DRIVE CIRCUIT**

RELAISANTRIEBSSCHALTUNG

CIRCUIT DE COMMANDE DE RELAIS

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Description

BACKGROUND OF THE INVENTION

5 1. FIELD OF THE INVENTION

[0001] The present invention relates to a relay drive circuit. Particularly, the present invention relates to a circuit configured to use semiconductor elements to drive a relay switch.

10 2. DESCRIPTION OF THE RELATED ART

[0002] Electric equipment using a relay switch has been broadly used. The relay switch includes, e.g., a relay switch with a relay coil and a movable piece. The relay coil operates as an electromagnet, and a current is applied to the relay coil such that the movable piece is attached to the relay coil. Moreover, the current flowing through the relay coil is blocked such that the movable piece is detached from the relay coil by a spring. When the movable piece is attached to the relay coil, a plurality of terminals provided at the relay switch are electrically connected together by the movable piece. When the movable piece is detached from the relay coil, these terminals are electrically disconnected from each other.

[0003] As described above, the relay switch is turned on or off between the terminals according to the current flowing through the relay coil, and therefore, control using a transistor configured to supply or block the current is facilitated. Patent literatures (JP-A-2014-116197, JP-A-10-255627, JP-A-2015-153555, JP-A-2015-095432, JP-A-2005-268134, JP-A-11-224580, JP-UM-A-01-001452) each describe the technique of controlling a relay switch by means of a transistor.

[0004] US 2014/0268473 A1 discloses a smart plug for coupling an electric vehicle to a power supply. The smart plug includes a relay and a microcontroller outputting a control signal to operate the relay. The relay includes a coil driver which may function as a current mirror.

SUMMARY OF THE INVENTION

[0005] A transistor circuit configured to control a relay switch includes, e.g., a transistor circuit configured to apply a predetermined drive voltage to a relay coil to turn on a relay switch. However, attachment of a movable piece of the relay switch to the relay coil often depends on the current flowing through the relay coil. For this reason, when a resistance value of the relay coil changes due to, e.g., a temperature change caused by heat generation, the relay switch is not driven under the same conditions even with a constant drive voltage. This might lead to a variation in current consumption and operation timing, for example.

[0006] An object of the present invention is to provide constant drive conditions of a relay switch.

[0007] The present invention is a relay drive circuit according to claim 1.

[0008] Preferably, the current suppression circuit includes a current suppression element configured to suppress, after conduction of the second semiconductor element has been made, the current flowing through the current suppression element itself as compared to that in conduction of the second semiconductor element, and a current setting element configured to divide a current flow for the current suppression element and to set the current flowing through the second current path.

[0009] Preferably, the current mirror circuit includes a first resistor element provided at a section of the first current path from a DC power supply to the first semiconductor element, and a second resistor element provided at a section of the second current path from the DC power supply to the second semiconductor element.

[0010] Preferably, a resistance value of the second resistor element is greater than a resistance value of the first resistor element.

[0011] According to the present invention, the constant drive conditions of the relay switch can be provided.

BRIEF DESCRIPTION OF THE DRAWINGS

50 **[0012]**

Fig. 1 is a diagram of a relay drive circuit;

Fig. 2 is a graph of a relationship between a collector current I_2 and a time;

Fig. 3 is a graph of a relationship among the collector currents I_1 , I_2 and the time; and

Fig. 4 is a diagram of the relay drive circuit.

DETAILED DESCRIPTION OF THE PREFERRED EMBODIMENTS

[0013] Fig. 1 illustrates a relay drive circuit of an embodiment of the present invention. This relay drive circuit is configured such that a relay switch 16 is driven by a current mirror circuit including a PNP transistor Q1, a first resistor element R1, a PNP transistor Q2, and a second resistor element R2. The relay switch 16 is connected to a collector terminal of the transistor Q1, and is turned on/off according to the current flowing through the collector terminal of the transistor Q1.

[0014] A configuration of the relay drive circuit will be described. A fifth resistor element R5 is connected between a control terminal 10 and a base terminal of an NPN transistor Q3. A sixth transistor element R6 is connected between the base terminal and an emitter terminal of the transistor Q3. The emitter terminal of the transistor Q3 is connected to an earth conductor.

[0015] A collector terminal of the transistor Q3 is connected to one end of each of a third resistor element R3 and a fourth resistor element R4. The other end of the fourth resistor element R4 is connected to one end of a capacitor C1, and the fourth resistor element R4 and the capacitor C1 connected in series are connected respectively to both ends of the third resistor element R3.

[0016] A collector terminal of the transistor Q2 is connected to a connection end between the third resistor element R3 and the capacitor C1. A base terminal of the transistor Q2 is connected to the collector terminal of the transistor Q2 itself. The second resistor element R2 is connected between an emitter terminal of the transistor Q2 and a supply terminal 14.

[0017] The third resistor element R3, the fourth resistor element R4, and the capacitor C1 form a current suppression circuit 26, and as described later, are configured to suppress, as time advances, the current flowing through the collector terminal of the transistor Q2 after the transistors Q3, Q2 have been turned on.

[0018] The base terminal of the transistor Q2 and a base terminal of the transistor Q1 are connected as a common terminal. The first resistor element R1 is connected between an emitter terminal of the transistor Q1 and the supply terminal 14. The relay switch 16 is connected between the collector terminal of the transistor Q1 and the earth conductor.

[0019] The relay switch 16 includes a relay coil 18, a diode 20, and a switch 22. One end of the relay coil 18 is connected to the collector terminal of the transistor Q1, and the other end of the relay coil 18 is connected to the earth conductor. An anode terminal of the diode 20 is connected to the earth conductor, and a cathode terminal of the diode 20 is connected to the collector terminal of the transistor Q1. That is, the diode 20 is connected in parallel to the relay coil 18 with the anode terminal of the diode 20 facing an earth conductor side.

[0020] A positive side of a DC power supply 12 is connected to the supply terminal 14. A negative side of the DC power supply 12 is connected to the earth conductor.

[0021] Next, operation of the relay drive circuit will be described. In an initial state, the voltage of the control terminal 10 is zero, and the charge voltage of the capacitor C1 is zero. The transistors Q1 to Q3 are OFF. No current flows through the relay coil 18, and the relay switch 16 is OFF.

[0022] When a control voltage Ctl applied to the control terminal 10 reaches a high voltage from zero, a current flows from the base terminal to the transistor Q3 via the fifth resistor element R5, and the transistor Q3 is turned on. Thus, the transistor Q3 is turned on such that conduction is made between the collector terminal and the emitter terminal. Note that a current with a value obtained by dividing a voltage between the base terminal and the emitter terminal of the transistor Q3 by a resistance value R6 flows from the sixth transistor element R6 to the earth conductor.

[0023] Since the transistor Q3 is turned on, the voltage of turning on the transistor Q2 is applied to between the emitter terminal and the base terminal of the transistor Q2 via the second resistor element R2 and the current suppression circuit 26. With this configuration, conduction is made between the emitter terminal and the collector terminal of the transistor Q2.

[0024] When the transistor Q2 is turned on, the charge voltage of the capacitor C1 is zero, and the capacitor C1 is in a short circuit state. Thus, when the transistor Q2 is ON, the current suppression circuit 26 has a resistance value $(R3//R4) = 1/(1/R3 + 1/R4)$ of the third resistor element R3 and the fourth resistor element R4 connected in parallel. Thus, initially when the transistor Q2 is turned on, an initial current I_{2s} represented by (Expression 1) flows from the emitter terminal to the collector terminal of the transistor Q2, where a supply voltage output from the DC power supply 12 is E.

$$\begin{aligned} \text{(Expression 1) } I_{2s} &= E/[R2 + (R3//R4)] \\ &= E/[R2 + R3 \cdot R4/(R3 + R4)] \end{aligned}$$

[0025] After the transistor Q2 has been turned on, the capacitor C1 is charged according to the properties set by each of resistance values R2, R3, R4 of the second resistor element R2, the third resistor element R3, and the fourth resistor element R4 and the electrostatic capacitance C1 of the capacitor C1, and the charge voltage of the capacitor C1 reaches the inter-terminal voltage of the third resistor element R3. With this configuration, the current flowing through the capacitor

C1 and the fourth resistor element R4 reaches zero, and a current flows only through the third resistor element R3 of the circuit elements forming the current suppression circuit 26. The current I_{2e} flowing from the emitter terminal to the collector terminal of the transistor Q2 after completion of charging of the capacitor C1 is the converging current I_{2e} represented by (Expression 2). Note that the emitter-collector voltage of the transistor Q2 is sufficiently lower than the supply voltage E.

$$\text{(Expression 2)} \quad I_{2e} = E/(R_2 + R_3)$$

[0026] Fig. 2 conceptually shows a relationship between the current (the collector current I_2) flowing from the emitter terminal to the collector terminal of the transistor Q2 and a time t . When the time $t = 0$, i.e., when the voltage of the control terminal 10 reaches the high voltage from zero and the transistor Q2 is turned on, the collector current I_2 is the initial current I_{2s} . Subsequently, the collector current I_2 decreases according to the properties set by each of the resistance values R_2 , R_3 , R_4 of the second resistor element R2, the third resistor element R3, and the fourth resistor element R4 and the electrostatic capacitance C1 of the capacitor C1, and converges to the converging current I_{2e} .

[0027] Next, operation of the current mirror circuit will be described. The current mirror circuit includes the transistor Q1, the first resistor element R1, the transistor Q2, and the second resistor element R2. The base terminal of the transistor Q2 is connected to the collector terminal of the transistor Q2 itself. The collector terminal of the transistor Q2 is connected to an upper end of the current suppression circuit 26, and therefore, the potential of the base terminal of the transistor Q2 is equal to the potential of the upper end of the current suppression circuit 26. Such a potential is also equal to the potential obtained by subtracting a voltage drop in the second resistor element R2 and the emitter-base voltage of the transistor Q2 from the supply voltage E.

[0028] In such a circuit configuration, when the collector current I_2 increases, the emitter-base voltage of the transistor Q2 decreases, and the collector current I_2 is brought into a decreasing state. Similarly, when the collector current I_2 decreases, the emitter-base voltage of the transistor Q2 increases, and the collector current I_2 is brought into an increasing state. That is, a negative feedback relationship is made between the emitter-base voltage of the transistor Q2 and the collector current I_2 . In the state in which an increase/decrease in the emitter-base voltage and an increase/decrease in the collector current I_2 are balanced out, the emitter-base voltage and the collector current I_2 are set, and the potential of the base terminal is further set.

[0029] The base terminal of the transistor Q1 is connected to the base terminal of the transistor Q2, and the first resistor element R1 is connected between the emitter terminal of the transistor Q1 and the supply terminal 14. The potential of the base terminal of the transistor Q1 is equal to the potential obtained by subtracting a voltage drop in the first resistor element R1 and the emitter-base voltage of the transistor Q1 from the supply voltage E. Moreover, the potential of the base terminal of the transistor Q1 is, by the base terminal of the transistor Q2, maintained at the potential depending on the collector current I_2 of the transistor Q2. With such a circuit configuration, when the collector current I_1 (the current flowing from the emitter terminal to the collector terminal of the transistor Q1) of the transistor Q1 increases, the emitter-base voltage of the transistor Q1 decreases, and the collector current I_1 is brought into a decreasing state. Similarly, when the collector current I_1 decreases, the emitter-base voltage of the transistor Q1 increases, and the collector current I_1 is brought into an increasing state. That is, a negative feedback relationship is made between the emitter-base voltage of the transistor Q1 and the collector current I_1 . In the state in which an increase/decrease in the emitter-base voltage and an increase/decrease in the collector current I_1 are balanced out, the emitter-base voltage and the collector current I_1 are set, and the potential of the base terminal is further set.

[0030] As described above, (i) the potential of the base terminal of the transistor Q2 is set in the state in which an increase/decrease in the emitter-base voltage of the transistor Q2 and an increase/decrease in the collector current I_2 are balanced out, (ii) the potential of the base terminal of the transistor Q1 is set in the state in which an increase/decrease in the emitter-base voltage of the transistor Q1 and an increase/decrease in the collector current I_1 are balanced out, and (iii) the potentials of the base terminals of the transistors Q1, Q2 are equal to each other.

[0031] Thus, under the condition where the emitter-base voltages of the transistors Q1, Q2 are equal to each other or the condition where the emitter-base voltages of the transistors Q1, Q2 are sufficiently lower than any of the voltage drop in the first resistor element R1 and the voltage drop in the second resistor element R2, $R_1 \cdot I_1 = R_2 \cdot I_2$ is satisfied. In this case, the collector current I_1 is (R_2/R_1) times higher than the collector current I_2 , and (Expression 3) is satisfied.

$$\text{(Expression 3)} \quad I_1 = (R_2/R_1) \cdot I_2$$

[0032] Fig. 3 conceptually shows a relationship between the collector current I_1 and the time t . When the time $t = 0$, i.e., when the voltage of the control terminal 10 reaches the high voltage from zero and the transistors Q3, Q2 are turned

on, the collector current I1 reaches the initial current I1s represented by (Expression 4).

$$\text{(Expression 4) } I1s = (R2/R1) \cdot I2s$$

$$= (R2/R1) \cdot E / [R2 + R3 \cdot R4 / (R3 + R4)]$$

[0033] Subsequently, the collector current I1 decreases according to the properties set by each of the resistance values R2, R3, R4 of the second resistor element R2, the third resistor element R3, and the fourth resistor element R4 and the electrostatic capacitance C1 of the capacitor C1, and converges to the converging current I1e represented by (Expression 5).

$$\text{(Expression 5) } I1e = (R2/R1) \cdot I2e$$

$$= (R2/R1) \cdot E / (R2 + R3)$$

[0034] Fig. 3 shows the collector current I2 in association with the collector current I1. In an example shown in this figure, the resistance value R2 of the second resistor element R2 is 2.5 times greater than the resistance value R1 of the first resistor element R1, and the collector current I1 is 2.5 times higher than the collector current I2.

[0035] The relay coil 18 is connected between the collector terminal of the transistor Q1 and the earth conductor, and the collector current I1 flows through the relay coil 18. The initial current I1e flows at the time at which the transistor Q1 is turned on, and the maximum current flows through the relay coil 18. This allows attachment of a movable piece 24 provided at the switch 22 to the relay coil 18, and the switch 22 is turned on. After the switch 22 has been turned on, the collector current I1 decreases, and converges to the converging current I1e. Thus, after the movable piece 24 has been attached to the relay coil 18, the current flowing through the relay coil 18 decreases, and converges to the converging current I1e.

[0036] Generally in a relay switch, a great current for moving a movable piece needs to be applied to a relay coil upon driving for attaching the movable piece to the relay coil. On the other hand, in a steady ON state after attachment of the movable piece to the relay coil, a current for maintaining an attachment state may flow through the relay coil.

[0037] According to the relay drive circuit of the present embodiment, the current flowing through the relay coil 18 is maximum upon driving, and decreases in the steady ON state. This reduces power consumption in the steady ON state, and suppresses heat generation of the relay coil 18.

[0038] By operation of the current mirror circuit, the properties of the collector current I1 in association with time passage are (R1/R2) times greater than the properties of the collector current I2. When a time until the collector current I1 converges from the initial current I1s to the converging current I1e is increased for reliable attachment of the movable piece 24 by the relay coil 18, a time until the collector current I2 converges from the initial current I2s to I2e may be increased. Such a time increases as the resistance value R3 of the third resistor element R3 or the electrostatic capacitance of the capacitor C1 increases.

[0039] In this state, as seen from (Expression 2) and (Expression 5), when the resistance value R3 increases, the converging current I2e and the converging current I1e decrease. Thus, there is a probability that a sufficient current for maintaining the attachment state of the movable piece 24 does not flow through the relay coil in the steady ON state.

[0040] For this reason, in the relay drive circuit of the present embodiment, each resistance value of the first resistor element R1 and the second resistor element R2 may be set based on a relationship between the resistance value R3 of the third resistor element R3 and the converging current I2e. That is, a relationship of $I2e = E / (R2 + R3)$ is, as shown in (Expression 2), satisfied between the resistance value R3 and the converging current I2e, and therefore, the ratio R2/R1 of the resistance value R2 to the resistance value R1 may be increased by the reduction ratio of the converging current I2e in association with an increase in the resistance value R3. This allows a sufficient current to flow through the relay coil 18 in the steady ON state. Further, the electrostatic capacitance of the capacitor C1 is not necessarily increased for increasing the time until the initial current I1s converges to the converging current I1e, and the dimensions of the capacitor C1 can be reduced.

[0041] Moreover, in the relay drive circuit of the present embodiment, the current flowing through the relay coil 18 is set by the collector current I1, and the collector current I1 is set by the collector current I2. The collector current I2 is set by the power voltage E, the resistance value R2 of the second resistor element R2, and the circuit constant of each element forming the current suppression circuit 26, and exhibits a low degree of dependence on a resistance value of the relay coil 18. Thus, the collector current

I1 also exhibits a low degree of dependence on the resistance value of the relay coil 18, and the current mirror circuit operates as a constant current source for the relay coil 18. Thus, even when the resistance value of the relay coil 18

changes due to, e.g., a temperature change, the relay switch 16 is driven under constant conditions. Even with a variation in the resistance value of the relay coil 18 according to products, the operation conditions of the relay switch 16 of each product are constant.

[0042] Note that in the operation of turning off the relay switch 16, the control voltage Ctl applied to the control terminal 10 reaches zero from the high voltage. This turns off the transistor Q3, thereby blocking the collector current I2. Further, the collector current I1 is also blocked. With blocking of the collector current I1, dielectric electromotive force is generated at the relay coil 18 with the earth conductor side being the positive side, and the current tends to continuously flow through the relay coil 18. The current based on the dielectric electromotive force flows in a direction from the anode terminal to the cathode terminal in the diode 20, and flows back in a closed circuit including the diode 20 and the relay coil 18. Thus, such a current decreases due to a resistive component of the relay coil 18. Moreover, the transistors Q2, Q3 are turned off such that the capacitor C1 discharges a charge to the third resistor element R3 and the fourth resistor element R4.

[0043] As described above, the relay drive circuit of the present embodiment includes the current mirror circuit, the current suppression circuit 26, and the transistor Q3 as a control switch. The current mirror circuit includes the transistor Q1 (a first semiconductor element), the first resistor element R1, the transistor Q2 (a second semiconductor element), and the second resistor element R2. The relay coil 18 is provided on a current supply path extending from the collector terminal of the transistor Q1 to the earth conductor.

[0044] The current mirror circuit is configured to adjust the current flowing through a first current path formed by the first resistor element R1, the transistor Q1, and the relay coil 18 according to the current flowing through a second current path formed by the second resistor element R2, the transistor Q2, the current suppression circuit 26, and the control switch (the transistor Q3).

[0045] The current suppression circuit 26 includes the capacitor C1 as a current suppression element configured to suppress, after conduction between the emitter terminal and the collector terminal of the transistor Q2 has been made, the current flowing through the current suppression element itself as compared to that in such conduction. This current suppression element may be a switch or other capacitive elements, for example. In the case of using the switch as the current suppression element, e.g., a control circuit is provided, which is configured to be ON when the transistor Q3 is turned on and to be OFF when a predetermined time is elapsed after the control circuit has been turned on. Moreover, the current suppression circuit 26 includes the third resistor element R3 as a current setting element configured to divide a current flow for the current suppression element to supply such a current toward the transistor Q3 and to set the current flowing through the second current path described above.

[0046] In addition to the third resistor element R3, a constant current diode may be used as the current setting element. In this case, an anode terminal of the constant current diode is connected to the collector terminal of the transistor Q2, and a cathode terminal of the constant current diode is connected to the collector terminal of the transistor Q3. In this case, the converging current I2e of the collector current I2 is defined by the constant current diode.

[0047] The circuit has been described above, in which the capacitor C1 and the fourth resistor element R4 are connected in series as the current suppression circuit 26 and the third resistor element R3 is connected in parallel to the capacitor C1 and the fourth resistor element R4 connected in series. The current suppression circuit 26 may be configured such that a portion corresponding to the fourth resistor element R4 is short-circuited instead of using the fourth resistor element R4. In this case, the initial collector current I2 and the initial collector current I1 are each represented by (Expression 1) and (Expression 4) where $R4 = 0$.

[0048] The circuit configuration has been described above, in which the PNP transistors are used as the transistor Q1 and the transistor Q2 and the NPN transistor is used as the transistor Q3. In addition to such a circuit configuration, NPN transistors may be used as the transistor Q1 and the transistor Q2, and a PNP transistor may be used as the transistor Q3. In this case, the polarities of the DC power supply 12 and the diode 20 are inverted as illustrated in Fig. 4.

[0049] Moreover, the circuit configuration has been described above, in which the transistor configured to operate as the control switch, such as the transistor Q3, is provided between the current suppression circuit 26 and the earth conductor. Such a transistor as the control switch may be provided between the supply terminal 14 and the second resistor element R2, between the second resistor element R2 and the emitter terminal of the transistor Q2, or between the collector terminal of the transistor Q2 and the current suppression circuit 26.

[0050] Further, the circuit configuration has been described above, in which the PNP transistors are used as the transistor Q1 and the transistor Q2 and the NPN transistor is used as the transistor Q3. In addition to such a circuit configuration, N-channel field-effect transistors may be used as the transistor Q1 and the transistor Q2, and a P-channel field-effect transistor may be used as the transistor Q3. Alternatively, P-channel field-effect transistors may be used as the transistor Q1 and the transistor Q2, and an N-channel field-effect transistor may be used as the transistor Q3. In this case, a gate terminal, a drain terminal, and a source terminal are connected respectively to points connected to a base terminal, a collector terminal, and an emitter terminal of each transistor.

[0051] The relay switch 16 driven by the relay drive circuit of the present embodiment may be an audio power amplifier speaker relay switch. Generally, the speaker relay switch is provided on a path extending from a power transistor of a

final stage to a speaker. ON-control of a speaker relay is, for example, performed after a power switch of an audio power amplifier has been turned on such that the audio power amplifier transitions from a transient state to a steady state. This avoids occurrence of great noise from the speaker when the power switch of the audio power amplifier is turned on.

[0052] In this case, a control signal for a change from zero to the high voltage is input to the control terminal 10 of the relay drive circuit of the present embodiment after a lapse of the time of transition of the audio power amplifier from the transient state to the steady state after the power switch of the audio power amplifier has been turned on. The relay drive circuit changes the voltage of the control terminal 10 to the high voltage, and turns on the speaker relay switch.

[0053] Moreover, when a short-circuit abnormality occurs at the speaker, an electrical burden on the power transistor might increase, and the life of the power transistor might be shortened. For this reason, the speaker relay may be controlled from ON to OFF when the current flowing through the power transistor exceeds a predetermined value. In this case, when the current flowing through the power transistor exceeds the predetermined value, a control signal for a change from the high voltage to zero is input to the control terminal 10 of the relay drive circuit of the present embodiment. The relay drive circuit changes the voltage of the control terminal 10 to zero, and turns off the speaker relay switch.

[0054] A DC power supply of the audio power amplifier includes, e.g., a DC power supply configured to rectify, after voltage lowering, the voltage of a commercial AC power supply to smooth the rectified voltage into a supply voltage by a capacitor without using a regulator IC. It might be difficult for such a DC power supply to drive the speaker relay with a constant current. According to the relay drive circuit of the present embodiment, even when the regulator IC is not used as the DC power supply, the speaker relay is driven with a constant current, and constant drive conditions are provided.

Claims

1. A relay drive circuit comprising:

a current mirror circuit including a first semiconductor element (Q1) and a second semiconductor element (Q2), the current mirror circuit being configured to adjust a current flowing through a first current path including the first semiconductor element (Q1) according to a current flowing through a second current path including the second semiconductor element (Q2); and

a control switch (Q3) provided on the second current path, wherein a relay coil (18) is provided on the first current path, the relay drive circuit further comprising:

a current suppression circuit (26) provided on the second current path and configured to suppress, after conduction of the second semiconductor element (Q2) has been made, the current flowing through the second current path as compared to that in the conduction of the second semiconductor element (Q2);

characterized in that

the current suppression circuit (26) includes:

a capacitor (C1) and a resistor element (R4) connected in series;

a current setting element (R3) connected in parallel such that a current flow is divided for the capacitor (C1) and the resistor element (R4) connected in series, and being configured to set the current flowing through the second current path.

2. The relay drive circuit according to claim 1, wherein the current setting element (R3) comprises a resistor element.

3. The relay drive circuit according to claim 1, wherein the current setting element (R3) comprises a constant current diode.

4. The relay drive circuit according to any one of claim 1 to claim 3, wherein the current mirror circuit includes

a first resistor element (R1) provided at a section of the first current path from a DC power supply (12) to the first semiconductor element (Q1), and

a second resistor element (R2) provided at a section of the second current path from the DC power supply (12) to the second semiconductor element (Q2).

5. The relay drive circuit according to claim 4, wherein

a resistance value of the second resistor element (R2) is greater than a resistance value of the first resistor element (R1).

5 Patentansprüche

1. Schaltkreis zur Ansteuerung eines Relais, umfassend:

10 einen Schaltkreis zum Spiegeln eines Stroms, der ein erstes Halbleiterelement (Q1) und ein zweites Halbleiterelement (Q2) umfasst, wobei der Schaltkreis zum Spiegeln eines Stroms zur Einstellung eines Stroms eingerichtet ist, der durch einen das erste Halbleiterelement (Q1) aufweisenden ersten Strompfad fließt, gemäß einem Strom, der durch einen das zweite Halbleiterelement (Q2) aufweisenden zweiten Strompfad fließt; und einen im zweiten Strompfad angeordneten Ansteuerungsschalter (Q3),
 15 wobei eine Relaisspule (18) im ersten Strompfad angeordnet ist und der Schaltkreis zur Ansteuerung eines Relais weiter umfasst:
 einen im zweiten Strompfad angeordneten Stromunterdrückungskreis (26), der eingerichtet ist, nachdem das zweite Halbleiterelement (Q2) leitend geschaltet wurde, zur Unterdrückung des durch den zweiten Strompfad fließenden Stroms im Vergleich zu dem beim Stromfluss durch das zweite Halbleiterelement (Q2);
dadurch gekennzeichnet, dass:
 20 der Stromunterdrückungskreis (26) umfasst:

einen Kondensator (C1) und ein Widerstandselement (R4), die in Reihe geschaltet sind;
 ein Element (R3) zum Einstellen eines Stroms, welches so parallel geschaltet ist, dass der Stromfluss für den Kondensator (C1) und das Widerstandselement (R4), die in Reihe geschaltet sind, aufgeteilt wird, und
 25 welches zur Einstellung des durch den zweiten Strompfad fließenden Stroms eingerichtet ist.

2. Schaltkreis zur Ansteuerung eines Relais nach Anspruch 1, wobei das Element (R3) zum Einstellen eines Stroms ein Widerstandselement umfasst.

30 3. Schaltkreis zur Ansteuerung eines Relais nach Anspruch 1, wobei das Element (R3) zum Einstellen eines Stroms eine Konstantstromdiode umfasst.

4. Schaltkreis zur Ansteuerung eines Relais nach einem der Ansprüche 1 bis 3, wobei der Schaltkreis zum Spiegeln eines Stroms beinhaltet 35 ein erstes Widerstandselement (R1), welches in einem von einer Gleichspannungsversorgung (12) zum ersten Halbleiterelement (Q1) reichenden Abschnitt des ersten Strompfads angeordnet ist, und ein zweites Widerstandselement (R2), welches in einem von der Gleichspannungsversorgung (12) zum zweiten Halbleiterelement (Q2) reichenden Abschnitt des zweiten Strompfads angeordnet ist.

40 5. Schaltkreis zur Ansteuerung eines Relais nach Anspruch 4, wobei ein Widerstandswert des zweiten Widerstandselements (R2) größer ist als ein Widerstandswert des ersten Widerstandselements (R1).

45 Revendications

1. Circuit d'excitation de relais, comprenant :

50 un circuit miroir de courant comprenant un premier élément semi-conducteur (Q1) et un second élément semi-conducteur (Q2), le circuit miroir de courant étant configuré pour régler un courant circulant à travers un premier trajet de courant comprenant le premier élément semi-conducteur (Q1) conformément à un courant circulant à travers un second trajet de courant comprenant le second élément semi-conducteur (Q2) ; et
 un commutateur de commande (Q3) disposé sur le second trajet de courant,
 dans lequel une bobine de relais (18) est disposée sur le premier trajet de courant,
 55 le circuit d'excitation de relais comprenant en outre :

un circuit de suppression de courant (26) disposé sur le second trajet de courant et configuré pour supprimer, après l'établissement d'une conduction du second élément semi-conducteur (Q2), le courant circulant à

travers le second trajet de courant par comparaison à celui correspondant à la conduction du second élément semi-conducteur (Q2) ;

caractérisé en ce que

le circuit de suppression de courant (26) comprend :

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un condensateur (C1) et un élément résistance (R4) connectés en série ;
un élément de fixation de courant (R3) connecté en parallèle de façon à diviser un flux de courant du condensateur (C1) et de l'élément résistance (R4) connectés en série, et configuré pour fixer le courant circulant à travers le second trajet de courant.

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2. Circuit d'excitation de relais selon la revendication 1, dans lequel l'élément de fixation de courant (R3) comprend un élément résistance.

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3. Circuit d'excitation de relais selon la revendication 1, dans lequel l'élément de fixation de courant (R3) comprend une diode à courant constant.

4. Circuit d'excitation de relais selon l'une quelconque des revendications 1 à 3, dans lequel le circuit miroir de courant comprend

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un premier élément résistance (R1) disposé au niveau d'une section du premier trajet de courant allant d'une alimentation en courant continu (12) au premier élément semi-conducteur (Q1), et
un second élément résistance (R2) disposé au niveau d'une section du second trajet de courant allant de l'alimentation en courant continu (12) au second élément semi-conducteur (Q2).

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5. Circuit d'excitation de relais selon la revendication 4, dans lequel une valeur de résistance du second élément résistance (R2) est supérieure à une valeur de résistance du premier élément résistance (R1).

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Fig. 1

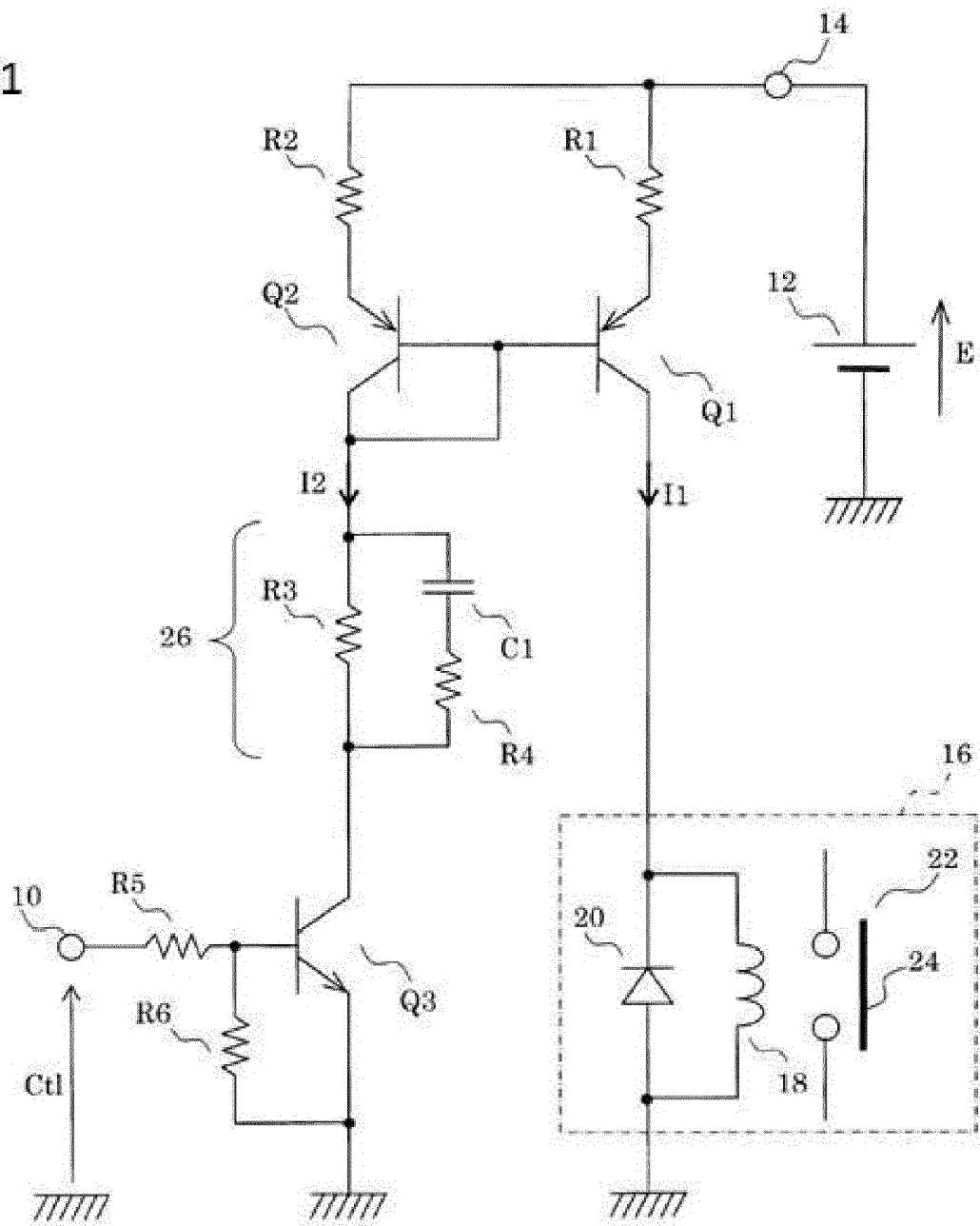


Fig. 2

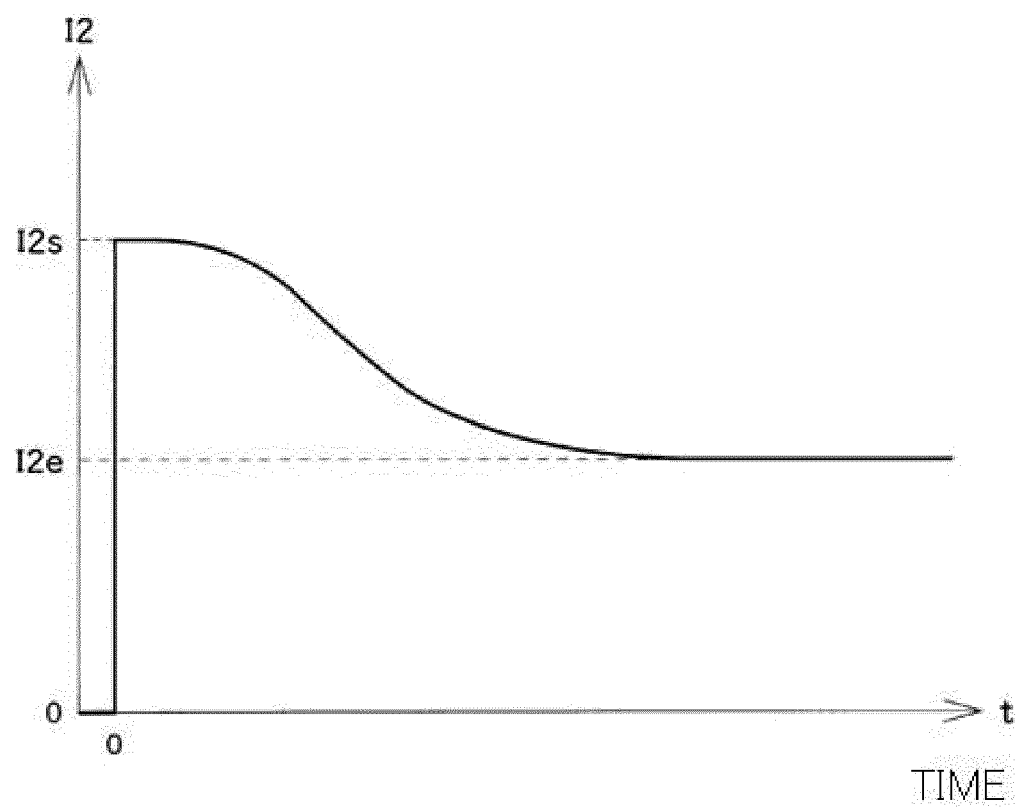


Fig. 3

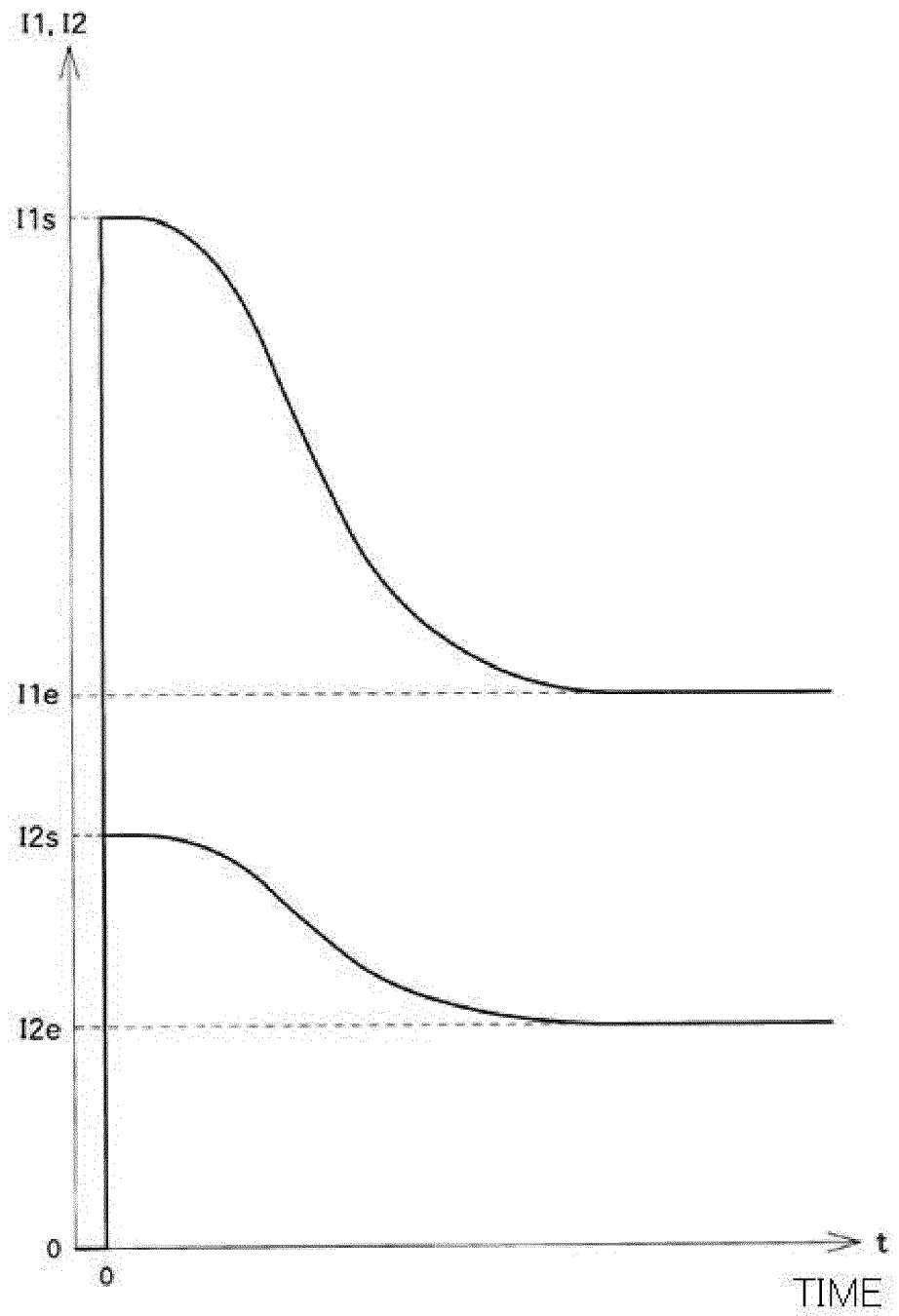
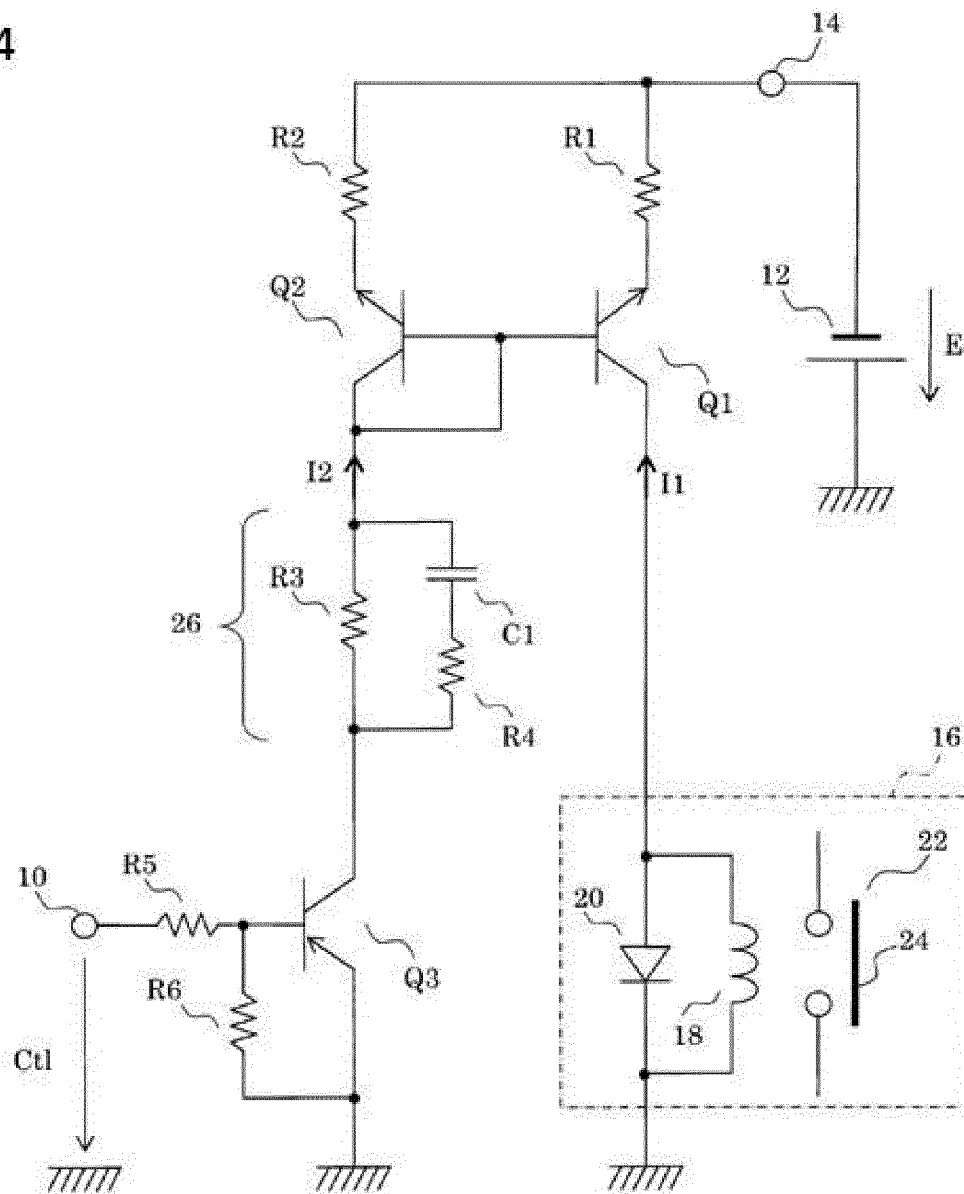


Fig. 4



REFERENCES CITED IN THE DESCRIPTION

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